Researchers develop stretchable quantum dot display

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Intrinsically stretchable quantum dot light-emitting diodes. Credit: *Nature Electronics* (2024). DOI: 10.1038/s41928-024-01152-w

A team of South Korean scientists led by Professor KIM Dae-Hyeong of the Center for Nanoparticle Research within the Institute for Basic
Science has pioneered a novel approach to stretchable displays. The team announced the first development of intrinsically stretchable quantum dot light-emitting diodes (QLEDs).

The findings are published in *Nature Electronics*.

In the rapidly evolving world of display technologies, the quest for creating intrinsically stretchable displays has been ongoing. Traditional displays, constrained by rigid and inflexible components, have struggled to evolve beyond flexible ones. There has been a clear need for novel materials and device designs that can endure significant stretching while maintaining their functionality, which is essential for applications including wearable and adaptable interfacing technologies.

The majority of the flexible displays on the market employ organic light-emitting diode (OLED) technology, which employs organic materials as light-emitting components. However, OLED often has drawbacks such as limited brightness and color purity issues. On the other hand, QLED displays offer excellent color reproduction, brightness, and longevity, making them a compelling choice for consumers who prioritize these factors.

However, the intrinsic challenge for developing flexible QLED displays lies in the nature of quantum dots (QDs) themselves; as 0-D inorganic nanoparticles, they do not possess inherent stretchability. There have been some attempts to embed QDs within elastic materials to create a light-emitting and elastic composite material.

A significant hurdle encountered during this approach was the elastomers' insulating properties, which impede the efficient injection of electrons and holes into the QDs, thereby diminishing the device's electroluminescent efficiency.
QD-based stretchable emission layer for intrinsically stretchable quantum dot light-emitting diodes. Schematic illustration of is-QLED based on the intrinsically stretchable emission layer. The stretchable EML is a ternary composite of QDs, SEBS-g-MA, and TFB, with a unique internal structure of phase separation. The TFB-rich islands at the bottom of stretchable EML facilitate the hole injection into QDs while minimizing excitation quenching sites, thus enhancing the device's efficiency and brightness. Credit: *Nature Electronics* (2024). DOI: 10.1038/s41928-024-01152-w

Hence the IBS researchers had to come up with innovations to overcome these limitations. Their work showcased the incorporation of a third material in the composite to enhance carrier delivery to the QDs. A \textit{p-type} semiconducting polymer, TFB, was employed to enhance both the stretchability of the device and the efficiency of hole injection. Adding TFB also improved the balance between the electron and hole injections.
An intriguing aspect of the ternary nanocomposite film was the distinctive internal structure exhibiting phase separation, where TFB-rich "islands" are formed at the base and QDs embedded in the SEBS-g-MA matrix lay on top of these islands. This unique structural arrangement minimizes exciton quenching sites and enhances hole injection efficiency, resulting in optimal device performance.

After careful selection and engineering of these materials, the IBS researchers achieved QLEDs with high brightness (15,170 cd m$^{-2}$), which is the highest among the stretchable LEDs, in addition to a low threshold voltage (3.2 V). The device did not suffer damage even when significant force was applied to stretch the material.

Even when stretched up to 1.5 times, there was no significant change in the distance between the quantum dots inside the device. For example, if a 20-inch QLED TV is made with this device, this means that the display performance will remain the same even when pulled to a 30-inch size.
Demonstrations of intrinsically stretchable quantum dot light-emitting diodes. The intrinsically stretchable QLEDs have a device structure where all the layers were engineered to have a sufficient level of stretchability. The stretchable QLEDs could be stretched to 50% with consistent device performance. Also, a passive matrix and full-color QLEDs were demonstrated. Credit: Nature Electronics (2024). DOI: 10.1038/s41928-024-01152-w

Co-first author Professor KIM Dong-chan explained, "Our research team has also developed a high-resolution patterning technology that can be applied to stretchable quantum dot light-emitting layers. By combining light-emitting materials and patterning technology, we demonstrated the potential of our device for RGB LEDs and complex applications like passive matrix arrays."
This research not only demonstrates the superior performance of QDs in stretchable displays but also sets a new direction for further enhancing device performance. Future research will focus on optimizing carrier injection efficiency and stretchability across all device layers. This finding lays a solid foundation for the next generation of QLED technology, promising a future where display technologies are not just flexible but truly stretchable, allowing new forms of wearable electronics and beyond.


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